NSN 5961-01-456-4614

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-456-4614 **Overall Length:** 1.800 inches **Overall Height:** 0.380 inches Overall Width: 1.690 inches **End Application:** Joint star (mmrs) e/i fscm 95542, nest higher assembly. P/n 2277-3555425 **Mounting Facility Quantity: Component Name And Quantity:** 4 transistor and 4 semiconductor device diode **Mounting Method:** Unthreaded hole **Features Provided:** Electrostatic sensitive **Voltage Rating In Volts Per Characteristic:** 500.0 breakdown voltage, collector-to-base, emitter open all transistor and 8.0 breakdown voltage, emitter-to-base, collector open all transistor **Current Rating Per Characteristic:** 20.00 amperes source cutoff current all transistor and 10.00 amperes source cutoff current all transistor **Power Rating Per Characteristic:** 200.0 watts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Dimensions exclusive of formed leads **Test Data Document:** C95542-161-1210 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 12 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**